# SEMICONDUCTOR IM

FAIRCHILD

# FDS6679

# 30 Volt P-Channel PowerTrench<sup>®</sup> MOSFET

### **General Description**

This P-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers, and battery chargers.

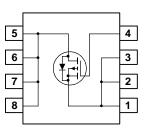
These MOSFETs feature faster switching and lower gate charge than other MOSFETs with comparable  $R_{\text{DS(ON)}}$  specifications.

The result is a MOSFET that is easy and safer to drive (even at very high frequencies), and DC/DC power supply designs with higher overall efficiency.

## Features

- -13 A, -30 V.  $R_{DS(ON)} = 9 \ m\Omega \ @ V_{GS} = -10 \ V$  $R_{DS(ON)} = 13 \ m\Omega \ @ V_{GS} = -4.5 \ V$
- Extended  $V_{\text{GSS}}$  range (±25V) for battery applications
- High performance trench technology for extremely low  $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





## Absolute Maximum Ratings T<sub>A=25°C</sub> unless otherwise noted

Symbol	Parameter		Ratings	Units	
V <sub>DSS</sub>	Drain-Source Voltage		-30	V	
V <sub>GSS</sub>	Gate-Source Voltage		±25	V	
ID	Drain Current – Continuous	(Note 1a)	-13	A	
	- Pulsed		-50		
PD	Power Dissipation for Single Operation	(Note 1a)	2.5	W	
		(Note 1b)	1.2		
		(Note 1c)	1.0		
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		-55 to +175	°C	
Therma	I Characteristics				
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W	
R <sub>eJC</sub>	Thermal Resistance, Junction-to-Case	(Note 1)	25	°C/W	

# Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
FDS6679	FDS6679	13"	12mm	2500 units
	•		•	

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FDS6679

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$	-30			V
<u>ΔBV<sub>DSS</sub></u> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		-23		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{\text{DS}} = -24 \text{ V},  V_{\text{GS}} = 0 \text{ V}$			-1	μΑ
I <sub>GSSF</sub>	Gate-Body Leakage, Forward	$V_{GS} = -25 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
I <sub>GSSR</sub>	Gate–Body Leakage, Reverse	$V_{GS} = -25 \text{ V},  V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-1	-1.6	-3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		5		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source	$V_{GS} = -10 \text{ V}, \qquad I_D = -13 \text{ A}$		7.3	9	mΩ
	On–Resistance	$V_{GS} = -4.5 \text{ V},  I_D = -11 \text{ A}$		10	13	
I <sub>D(on)</sub>	On–State Drain Current	$\label{eq:VGS} \begin{array}{c} V_{GS}{=}{-}10 \ V, \ I_{D} = {-}13 \ A, \ T_{J}{=}125^{\circ}C \\ V_{GS} = {-}10 \ V,  V_{DS} = {-}5 \ V \end{array}$	-50	9.5	13	A
g <sub>FS</sub>	Forward Transconductance	$V_{DS} = -5 V$ , $I_D = -13 A$	50	44		s
-						
	Characteristics	$V_{DS} = -15 V$ , $V_{GS} = 0 V$ ,		3939		pF
C <sub>iss</sub>	Output Capacitance	$V_{DS} = -15 V$ , $V_{GS} = 0 V$ , f = 1.0 MHz		972		pr
	Reverse Transfer Capacitance			498		pr pF
	·			400		Pi
	<b>IG Characteristics</b> (Note 2) Turn–On Delay Time	1 - 15 $1 - 10$		19	34	ns
t <sub>d(on)</sub> t <sub>r</sub>	Turn-On Rise Time	$V_{DD} = -15 \text{ V}, \qquad I_D = -1 \text{ A}, \\ V_{GS} = -10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		10	20	ns
	Turn-Off Delay Time			110	176	ns
t <sub>d(off)</sub> t <sub>f</sub>	Turn–Off Fall Time	-		65	104	ns
Q <sub>a</sub>	Total Gate Charge	$V_{DS} = -15 \text{ V}, \qquad I_D = -13 \text{ A},$		71	100	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS} = -10 V$		12	100	nC
Q <sub>gd</sub>	Gate-Drain Charge	-		15		nC
		and Movimum Potings	1		1	L
Drain-50	ource Diode Characteristics				-2.1	A
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \text{ V},  I_S = -2.1 \text{ A}  (\text{Note 2})$		0.7	-1.2	V



a) 50°C/W (10 sec)
62.5°C/W steady state when mounted on a 1in<sup>2</sup> pad of 2 oz copper

b) 105°C/W when mounted on a .04 in<sup>2</sup> pad of 2 oz copper

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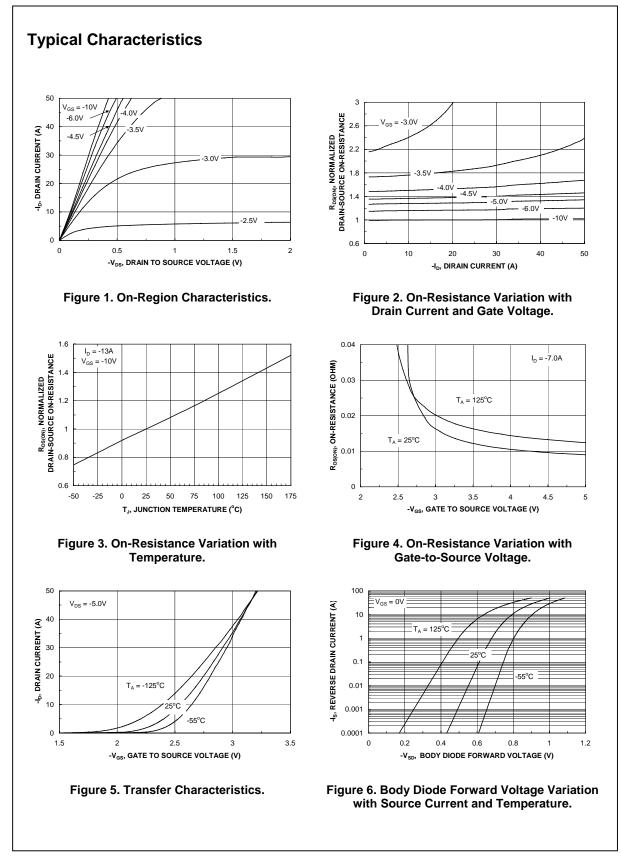
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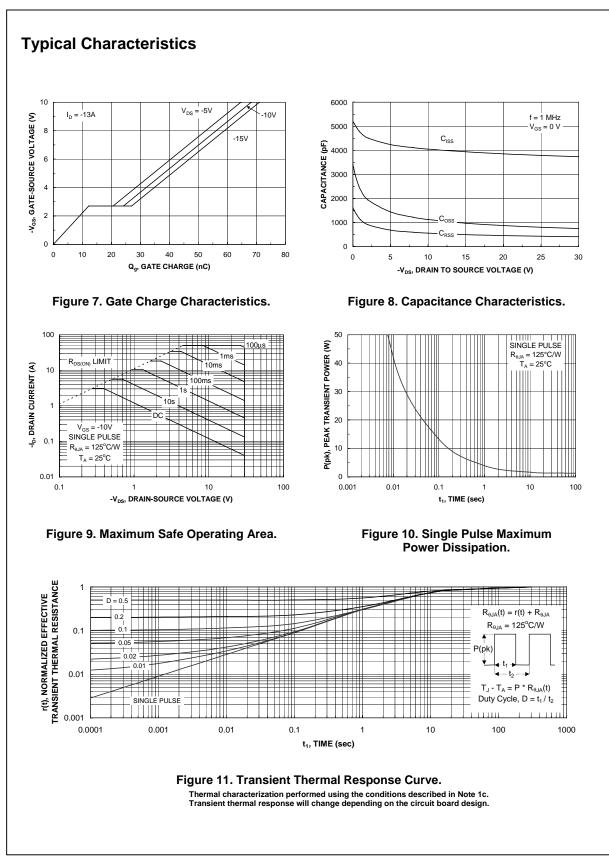
c) 125°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300 $\mu$ s, Duty Cycle < 2.0%

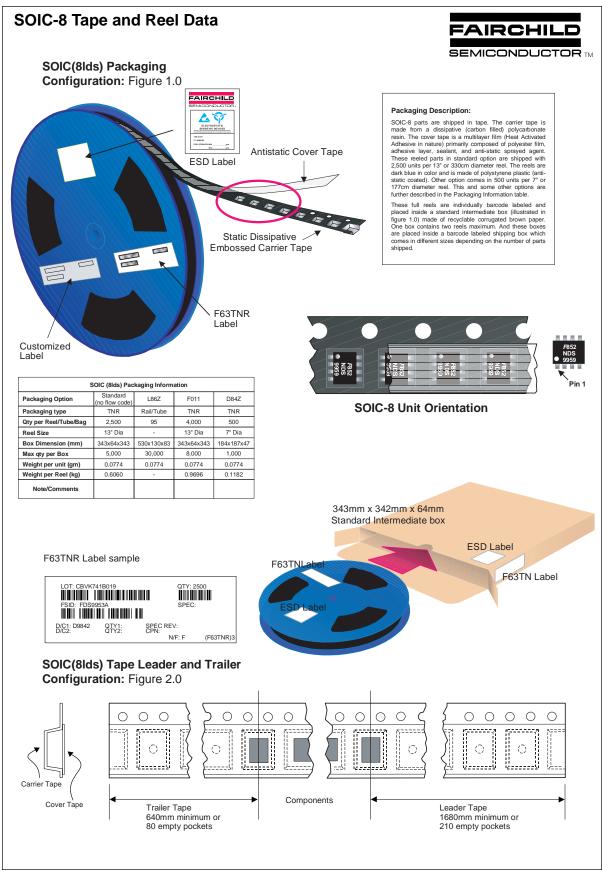


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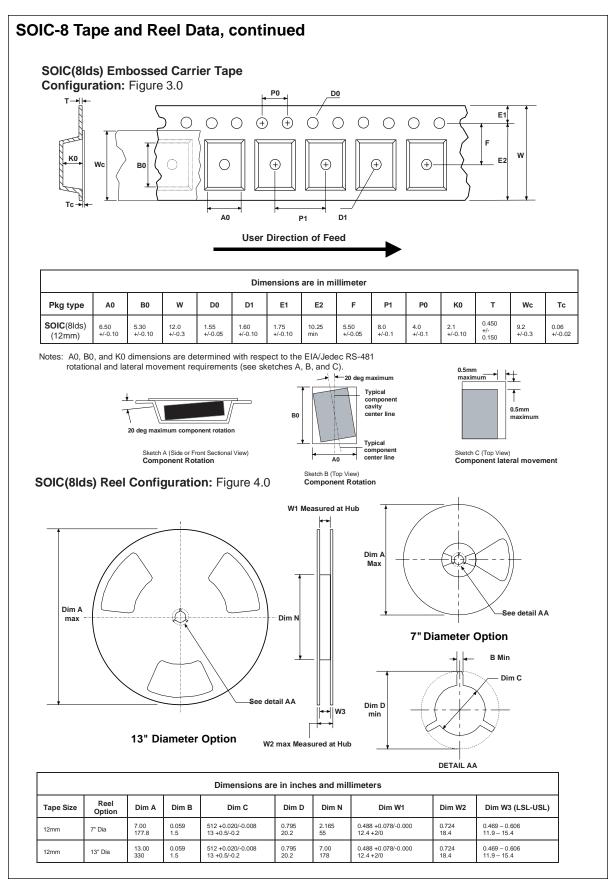
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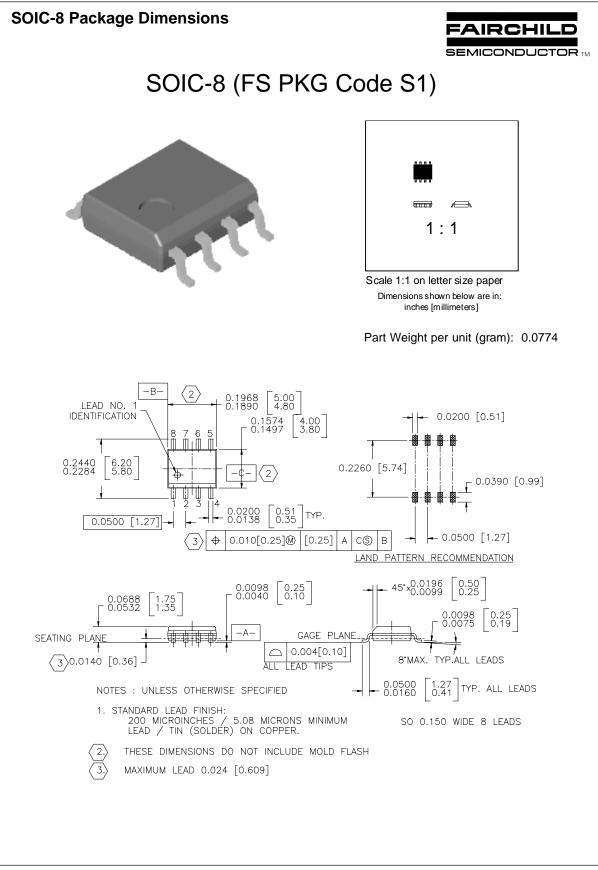
FDS6679 Rev B(W)



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### PRODUCT STATUS DEFINITIONS

**Definition of Terms** 

| Datasheet Identification | Product Status            | Definition                                                                                                                                                                                                                        |
|--------------------------|---------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Advance Information      | Formative or<br>In Design | This datasheet contains the design specifications for<br>product development. Specifications may change in<br>any manner without notice.                                                                                          |
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| No Identification Needed | Full Production           | This datasheet contains final specifications. Fairchild<br>Semiconductor reserves the right to make changes at<br>any time without notice in order to improve design.                                                             |
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|                          | 1                         | Rev G                                                                                                                                                                                                                             |